

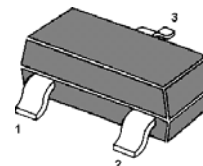
NPN Silicon Epitaxial Planar Transistors

Features

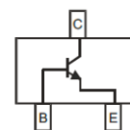
- These transistors are subdivided into three groups -16, -25 and -40, according to their current gain.
- As complementary types the NPN transistors ABC817 and ABC818 are recommended.
- Halogen and Antimony Free(HAF), RoHS compliant
- AEC-Q101 Qualified
- For switching, AF driver and amplifier applications



RoHS
COMPLIANT



1.Base 2. Emitter 3. Collector



Mechanical Data

- SOT-23 Plastic Package
- Mounting position: Any

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector Base Voltage ABC817 ABC818	V_{CBO}	50 30	V
Collector Emitter Voltage ABC817 ABC818	V_{CEO}	45 25	V
Emitter Base Voltage	V_{EBO}	5	V
Collector Current	I_C	500	mA
Power Dissipation ¹⁾	P_D	300	mW
Operating Junction Temperature Range	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^{\circ}\text{C}$

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance Junction to Ambient ¹⁾	R_{thJA}	417	$^{\circ}\text{C/W}$

¹⁾ Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Electrical Characteristics (T _A =25°C unless otherwise noted)						
Parameter		Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at V _{CE} = 1 V, I _C = 100 mA	-16	h _{FE}	100	-	250	-
	-25	h _{FE}	160	-	400	-
	-40	h _{FE}	250	-	600	-
		h _{FE}	40	-	-	-
at V _{CE} = 1 V, I _C = 500 mA						
Collector Base Cutoff Current at V _{CB} = 20 V		I _{CBO}	-	-	100	nA
Emitter Base Cutoff Current at V _{EB} = 5 V		I _{EBO}	-	-	100	nA
Collector Base Breakdown Voltage at I _C = 10 μA	ABC817 ABC818	V _{(BR)CBO}	50 30	-	-	V
Collector Emitter Breakdown Voltage at I _C = 10 mA	ABC817 ABC818	V _{(BR)CEO}	45 25	-	-	V
Emitter Base Breakdown Voltage at I _E = 10 μA		V _{(BR)EBO}	5	-	-	V
Collector Emitter Saturation Voltage at I _C = 500 mA, I _B = 50 mA		V _{CE(sat)}	-	-	0.7	V
Base Emitter On Voltage at I _C = 500 mA, V _{CE} = 1 V		V _{BE(on)}	-	-	1.2	V
Transition Frequency at V _{CE} = 5 V, I _C = 10 mA, f = 100 MHz		f _T	100	-	-	MHz
Collector Output Capacitance at V _{CB} = 10 V, f = 1 MHz		C _{ob}	-	5	-	pF

Typical Characteristics Curves

Fig. 1 Output Characteristics Curve

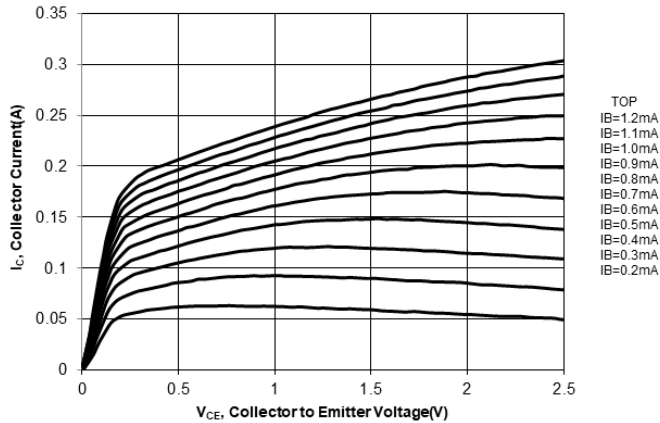


Fig. 2 Collector Current vs. Base to Emitter Voltage

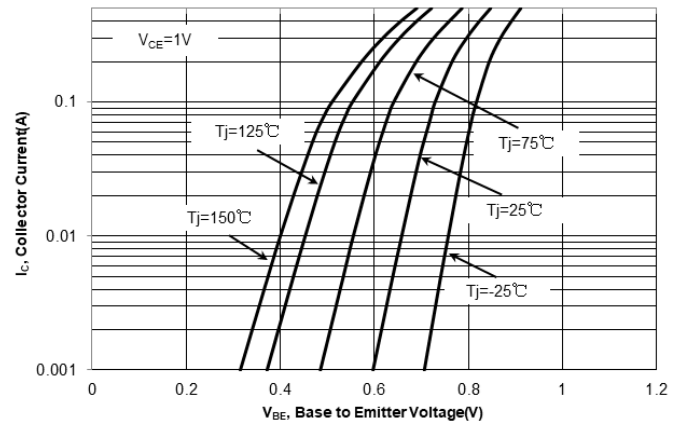


Fig. 3 DC Current Gain vs. Collector Current

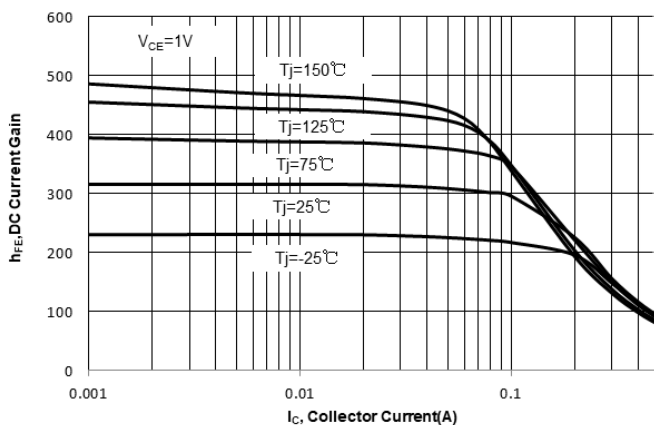


Fig. 4 $V_{BE(sat)}$ vs. Collector Current

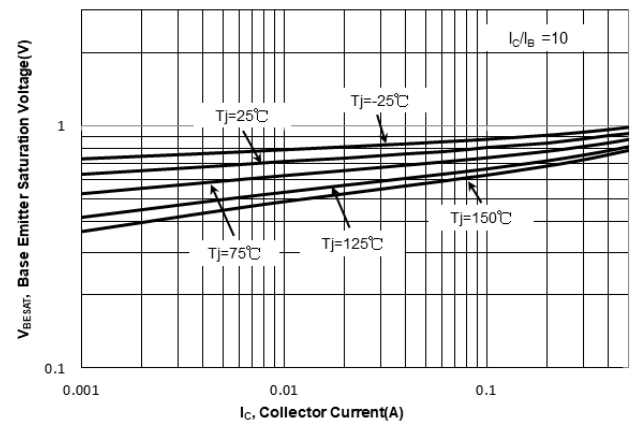


Fig. 5 $V_{CE(sat)}$ vs. Collector Current

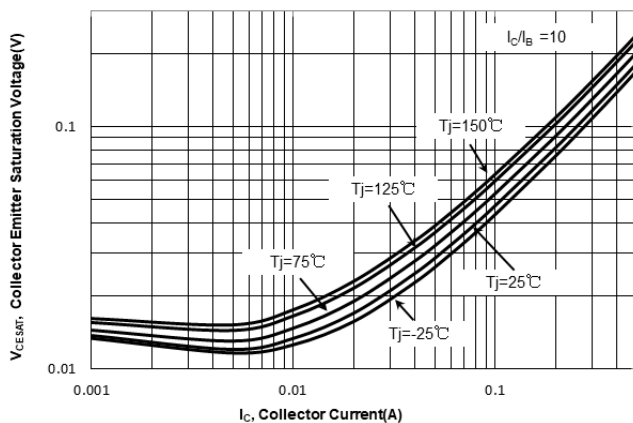


Fig. 6 Output Capacitance

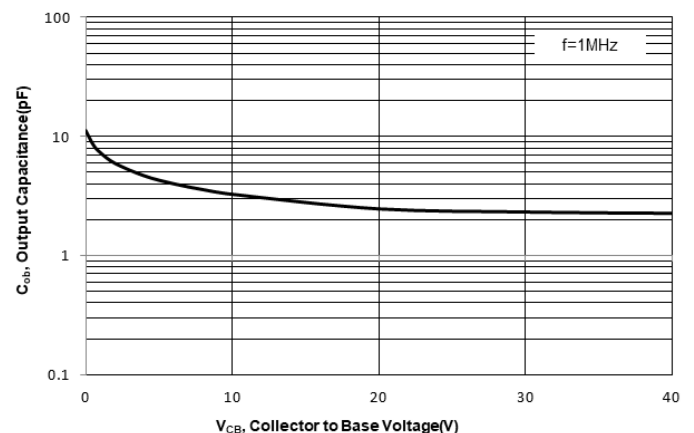
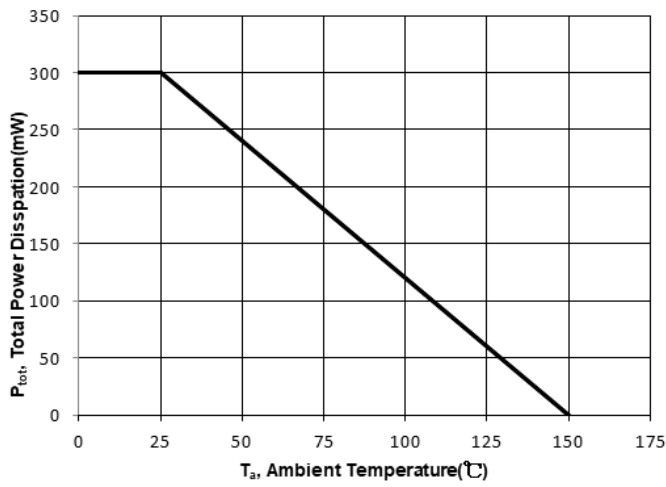
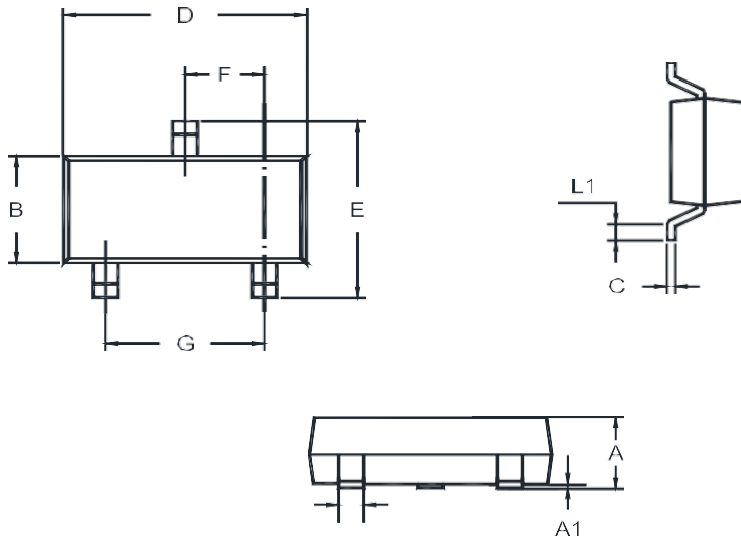


Fig. 7 Power Derating Curve



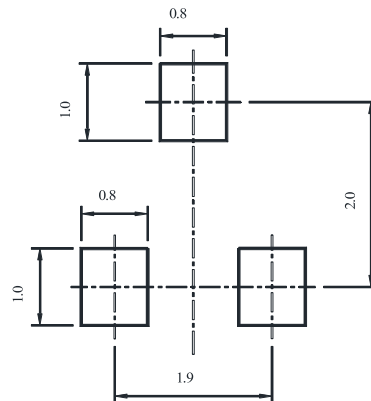
Package Outline Dimensions (Unit: millimeters)

SOT-23



SYMBOL	MILLIMETER		
	MIN	TYP	MAX
A	0.89	/	1.2
A1	0.013	/	0.1
B	1.2	/	1.4
C	0.08	/	0.19
D	2.8	/	3.04
E	2.2	/	2.6
F	0.89	/	1.02
G	1.78	/	2.04
L	0.37	/	0.51
L1	/	/	0.2

Recommended Soldering Footprint (Unit: millimeters)



Packing Information

Package	Tape Width	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-23	8	4±0.1	0.157±0.004	178	7	3000

Marking information

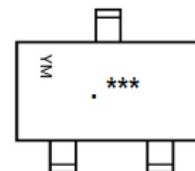
Part No.	Marking Code
ABC817-16 & ABC818-16	6CR
ABC817-25 & ABC818-25	6CS
ABC817-40 & ABC818-40	6CT

" *** " = See table of Marking information

" YM " = Date Code Marking

" • " = Automotive-grade material

Font type: Arial



Revision History

Version	Date	Major Changes
Rev.A	2025.01.19	Official Release

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